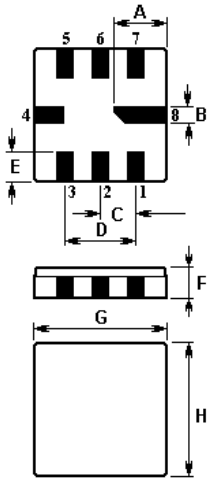
Tel : +44 118 979 1238
Fax : +44 118 979 1283
Email: info@actcrystals.com

The **ACTQ550/433.92/QCC8C** is a two-port, 180° surface-acoustic-wave (**SAW**) resonator in a surface-mount ceramic **QCC8C** case. It provides reliable, fundamental-mode, quartz frequency stabilization i.e. in transmitters or local oscillators operating at **433.920** MHz.

1. Package Dimension (QCC8C)

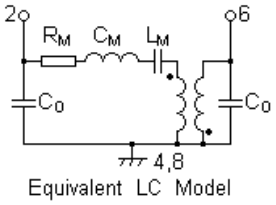


2.

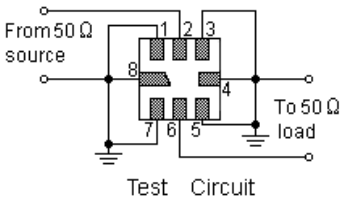
Pin	Configuration
2	Input / Output
6	Output / Input
4,8	Case Ground
1,3,5,7	N C

Sign	Data (unit: mm)	Sign	Data (unit: mm)
A	2.08	E	1.2
B	0.6	F	1.35
C	1.27	G	5.0
D	2.54	H	5.0

3. Equivalent LC Model and Test Circuit



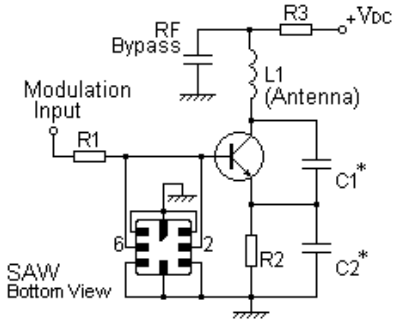
Equivalent LC Model



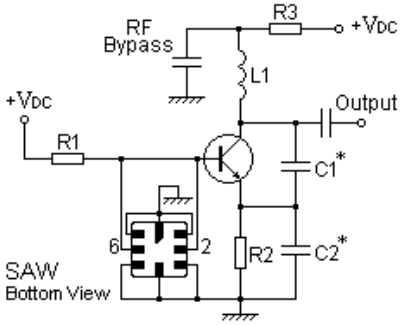
Test Circuit

4. Typical Application Circuits

1) Low-Power Transmitter Application



2) Local Oscillator Application



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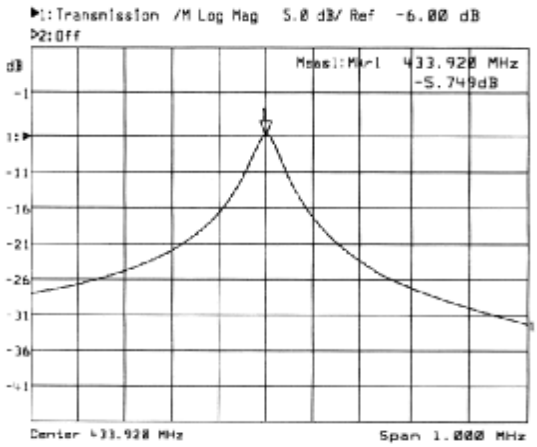
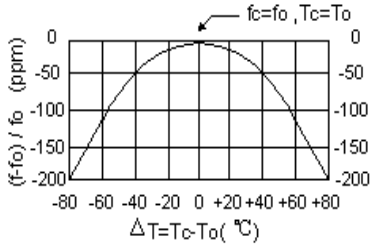
5. Typical Frequency Response



6. Temperature Characteristics



The curve shown above accounts for resonator contribution only and does not include LC component temperature characteristics.

7. Performance

7-1.Maximum Ratings

Rating		Value	Unit
CW RF Power Dissipation	P	10	dBm
DC Voltage Between Terminals	V_{DC}	±30	V
Storage Temperature Range	T_{stg}	-40 to +85	°C
Operating Temperature Range	T_A	-10 to +60	°C

7-2.Electronic Characteristics

Characteristic		Sym	Minimum	Typical	Maximum	Unit
Centre Frequency (+25°C)	Absolute Frequency	f_C	433.845		433.995	MHz
	Tolerance from 433.920 MHz	Δf_C		±75		kHz
Insertion Loss		IL		6.0	8.0	dB
Quality Factor	Unloaded Q	Q_U		15,040		
	50 Ω Loaded Q	Q_L		7,500		
Temperature Stability	Turnover Temperature	T_O	25		55	°C
	Turnover Frequency	f_O		fc		kHz
	Frequency Temperature Coefficient	FTC		0.032		ppm/°C^2
Frequency Aging	Absolute Value during the First Year	$\|f_A\|$		≤10		ppm/yr
DC Insulation Resistance Between Any Two Terminals			1.0			MΩ
RF Equivalent RLC Model	Motional Resistance	R_M		99.5	151	Ω
	Motional Inductance	L_M		549.079		µH
	Motional Capacitance	C_M		0.24526		fF
	Shunt Static Capacitance	C_O	1.10	1.30	1.60	pF

In keeping with our ongoing policy of product evolvement and improvement, the above specification is subject to change without notice.

ISO9001: 2000 Registered - Registration number 6830/2

Issue : 1 C1

Date : SEPT 04

For quotations or further information please contact us at:
3 The Business Centre, Molly Millars Lane, Wokingham, Berks, RG41 2EY, UK
http://www.actcrystals.com

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Fax : +44 118 979 1283
Email: info@actcrystals.com

CAUTION: Electrostatic Sensitive Device. Observe precautions for handling!

1. The frequency f_C is the frequency of minimum IL with the resonator in the specified test fixture in a 50 Ω test system with VSWR≤1.2:1.
2. Unless noted otherwise, case temperature T_C = +25°C±2°C.
3. Frequency aging is the change in f_C with time and is specified at +65°C or less. Aging may exceed the specification for prolonged temperatures above +65°C. Typically, aging is greatest the first year after manufacture, decreasing in subsequent years.
4. Turnover temperature, T_0, is the temperature of maximum (or turnover) frequency, f_0. The nominal frequency at any case temperature, T_C, may be calculated from: $f = f_0 [1 - FTC (T_0 - T_C)^2]$.
5. This equivalent RLC model approximates resonator performance near the resonant frequency and is provided for reference only. The capacitance C_0 is the measured static (non-motional) capacitance between input terminal and ground or output terminal and ground. The measurement includes case parasitic capacitance.
6. Derived mathematically from one or more of the following directly measured parameters: f_C, IL, 3 dB bandwidth, f_C versus T_C, and C_0.
7. The specifications of this device are based on the test circuit shown above and subject to change or obsolescence without notice.
8. Typically, equipment utilizing this device requires emissions testing and government approval, which is the responsibility of the equipment manufacturer.
9. Our liability is only assumed for the Surface Acoustic Wave (SAW) component(s) per se, not for applications, processes and circuits implemented within components or assemblies.